

Periodic Ripples in a free Smectic A Surface Skin

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A smectic A skin in a homeotropic texture on a liquid surface should form a periodic ripple when a horizontal compressive strain exceeds a critical value. The ripple wavelength is proportional to the fourth root of the skin thickness. In all practical cases the critical strain should be inversely proportional to the skin thickness. For a skin thickness approaching molecular dimensions, the critical strain has to be kept low by a small surface tension in order to avoid the formation of dislocations.

A solid elastic skin laid on the horizontal surface of a liquid acquires a periodic ripple formation when a horizontal compressive strain exceeds a critical value¹. The ripple amplitude grows with the square root of the excess strain. This instability can be interpreted as a kind of second order phase transition. The ripple wavelength is proportional to the 3/4th power of the skin thickness. This result suggests that the same considerations apply to a smectic A skin which has its molecular layers parallel to the plane surface of the isotropic liquid.

From a smectic A layer with the same homeotropic texture, strongly anchored between parallel plane plates, one already knows some transitions induced by external fields. This so called Helfrich-Hurault effect² describes the formation of an internal periodic deformation along the layer plane. It can be caused either by a critical magnetic field parallel to the layer ($\chi_a > 0$)² or by tension normal to the plates³. A related thermo-optical effect observed by Kahn⁴ produces the needed underpressure by suddenly cooling the layer, after it has been heated by light absorption. In all these cases, the ripple wavelength is proportional to the square root of the layer thickness.

The effect to be described in this paper differs from those named before in so far as no solid walls exist to which the smectic A skin is fixed. This will result in another power law between the ripple wavelength and the skin thickness. The results, however, are comparable to those obtained from a solid elastic skin.

In orthogonal coordinates (Fig. 1 a), the smectic A skin has the thickness d in the z direction and the length L in the x direction. It undergoes a compressive strain ΔL in the x direction. The y dimension may be kept constant. The displacement vector $(u_x, 0, u_z)$ has a zero y component and the other components do not depend on y . The strain may be applied in an adiabatic way so that the number of molecular layers remains unchanged. They only increase their thickness and may undergo an x dependent modulation. This can be described by the z and x dependence of u_z . In an approximation where the density of the smectic A liquid crystal remains constant, one obtains the following expression for the free energy density F ⁵:

$$F = \frac{1}{2} \bar{B} u_{z,z}^2 + \frac{1}{2} K_1 u_{z,xx}^2. \quad (1)$$

\bar{B} is an elastic module which characterizes the resistance of a molecular skin against a change in thickness. K_1 is the elastic splay constant. In this approximation we are not able to describe the strain induced rippling. As already shown in other examples⁶ one has to replace $u_{z,z} = \Delta a/a_0$ (see Fig. 1 b) by $\Delta a/a_0 = \Delta a_0/a_0 - \frac{1}{2} u_{z,x}^2$. This ap-

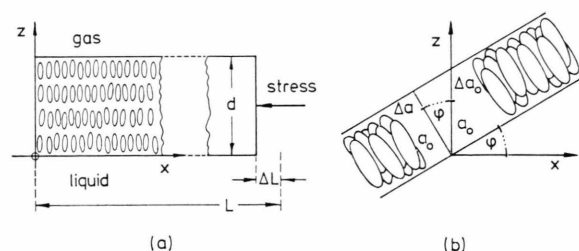


Fig. 1. a) Coordinate system for the smectic A skin on the liquid surface. $\Delta L/L$ is the applied compressive strain. b) Molecular layer in oblique orientation. Δa is the actual increase of the original thickness a_0 .

proximation still holds for small angles φ . a_0 is the thickness of an undeformed molecular layer. Because of the incompressibility assumed for the smectic A

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skin $\Delta a_0/a_0$ comes out to be equal to $(\Delta L/L)$. From the modified Eq. (1) and by adding the terms for gravity and for surface tensions we obtain the free energy per surface area

$$f(x) = \frac{1}{2} \bar{B} d (\Delta L/L - \frac{1}{2} u_{z,x}^2)^2 + \frac{1}{2} K_1 d u_{z,xx}^2 + \frac{1}{2} \varrho g u_z^2 + \frac{1}{2} \gamma u_{z,x}^2. \quad (2)$$

ϱ means the density of the isotropic liquid (or when stratified with another liquid, the difference in densities) and γ means the sum of surface tensions of both the upper and lower side of the skin. On account of the absence of solid walls there is no z dependence of f .

Actually one should apply variational methods to minimize $f(x)$. This would give a nonlinear differential equation of fourth order in u_z . However, near the expected 'phase transition', that means for small ripple amplitudes, we may use the harmonic approximation

$$u_z = \zeta_0 \cos kx \quad (3)$$

in Equation (2). We may average $f(x)$ over one wavelength $\lambda = 2\pi/k$ and by using $\langle \sin^2 kx \rangle = \langle \cos^2 kx \rangle = 1/2$ and $\langle \sin^4 kx \rangle = 3/8$ we obtain the mean free energy per unit-area in Landau's meaning

$$f = f_0 + f_{II} \zeta_0^2 + f_{IV} \zeta_0^4 \quad (4)$$

where the coefficients have the following form:

$$f_0 = \frac{1}{2} \bar{B} d (\Delta L/L)^2, \quad (5)$$

$$f_{II} = \frac{1}{4} [-\bar{B} d (\Delta L/L) k^2 + K_1 d k^4 + \varrho g + \gamma k^2], \quad (6)$$

$$f_{IV} = \frac{3}{64} \bar{B} d k^4. \quad (7)$$

A comparison of Eqs. (5) and (6) with the corresponding expressions for the solid skin¹ shows a completely analogous form. One only has to replace \bar{B} by the Young modulus E of the solid skin and K_1 by $E d^2/12$. In our approximation a single molecular smectic A skin ($d = a_0$) behaves like a solid elastic skin of the same thickness. And a smectic A skin of thickness $d = n a_0$ behaves like a file of n solid layers of thickness a_0 freely sliding face by face. A vivid example of the reduced bending stiffness is given by a file of papers, compared with a wooden plate of the same size. Hence in the approximation used here we should get

$$K_1/\bar{B} = a_0^2/12. \quad (8)$$

However one knows that when approaching the smectic A-nematic transition point \bar{B} will go to

zero. So Eq. (8) might be only useful sufficiently away from this transition point.

The further steps are the same as for the solid skin. For a better understanding, the following analogy to the ferromagnetic phase transition may help: $(\Delta L/L)$ behaves in the same way as a reduction in temperature $-\Delta T$; ζ_0 the same as the spontaneous magnetisation M , and hence it can be used as an order parameter. Because $f_{IV} > 0$ we need not consider higher powers in ζ_0^2 . We expect a second order phase transition when f_{II} changes sign. This happens for $(\Delta L/L) = (\Delta L/L)_0$ where

$$\left(\frac{\Delta L}{L}\right)_0 = \frac{K_1}{\bar{B}} \cdot k^2 + \frac{\gamma}{\bar{B} d} + \frac{\varrho g}{\bar{B} d} \cdot \frac{1}{k^2} \quad (9)$$

as a function of k has a minimum for the critical wavenumber k_c :

$$k_c = (\varrho g/K_1 d)^{1/4} \quad \text{or} \quad \lambda_c = 2\pi (K_1 d/\varrho g)^{1/4}. \quad (10)$$

That is the wavelength of the spontaneous rippling as soon as $(\Delta L/L)$ surpasses the critical value

$$\left(\frac{\Delta L}{L}\right)_c = \frac{1}{\bar{B} d} [\gamma + 2(K_1 \varrho g d)^{1/2}]. \quad (11)$$

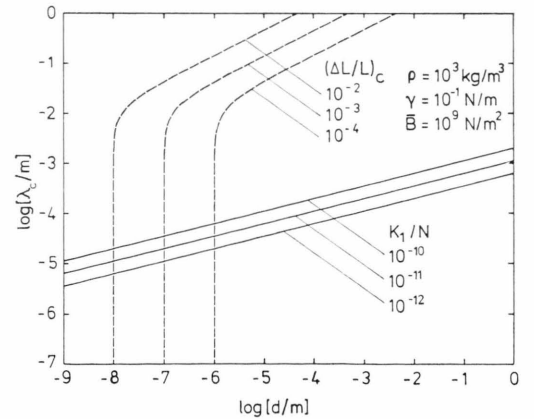


Fig. 2. Ripple wavelength λ_c vs skin thickness d (log-log plot). Solid lines: Splay constant K_1 as parameter [see Equation (10)]. Dashed lines: Critical strain $(\Delta L/L)_c$ as parameter [see Equation (12)].

In Fig. 2 λ_c is plotted against d from Eq. (10) on a double logarithmic scale (solid straight lines). For ϱ the density of water has been chosen. K_1 is the free parameter. Below a thickness of about 10^{-4} m λ_c remains larger than d . Down to a skin thickness of

molecular dimensions λ_c should be observable in the microscope.

By using K_1 out of Eq. (10) to replace it in Eq. (11) one obtains

$$\lambda_c^2 = \frac{2\pi^2}{\varrho g} \left[\bar{B} d \left(\frac{\Delta L}{L} \right)_c - \gamma \right]. \quad (12)$$

The dashed curves in Fig. 2 show this relation between λ_c and d when $(\Delta L/L)_c$ acts as a free parameter. The other parameters have been reasonably fixed as $\bar{B} = 10^9 \text{ N/m}^2$ and $\gamma = 10^{-1} \text{ N/m}$. In the region of the solid straight lines the dashed lines are parallel to the λ_c axis. In all practical cases $\gamma \gg (K_1 \varrho g d)^{1/2}$ in Equation (11). Therefore a good approximation is

$$(\Delta L/L)_c \cong \gamma / \bar{B} d. \quad (13)$$

For $d > 10^{-6} \text{ m}$ $(\Delta L/L)_c$ is sufficiently small so that plastic effects like the motion of dislocations into the skin will not take place before the rippling sets in. In order to avoid such difficulties in a thinner skin the surface tension γ has to be reduced drastically.

The simultaneous action of a magnetic field in the z or x direction is shown to be inefficient in practice. Its contribution to f_{II} in Eq. (6) has the form $\pm \frac{1}{4} (\mu_0 \chi_a H^2 d) k^2$ and formally it acts in the same way as the surface tension. Therefore in Eqs. (11), (12), and (13) γ has to be replaced by $(\gamma \pm \mu_0 \chi_a H^2 d)$. However for small skin thicknesses d this magnetic term can be neglected for all practical fields.

As for the solid skin¹, the critical wavelength of the smectic A skin is independent of the stationary amplitude z_0 . This equilibrium amplitude is obtained from Eq. (4) by minimizing f with respect to the amplitude z_0 : $\partial f / \partial z_0^2 = 0$ gives $z_0^2 = -f_{II} / 2 f_{IV}$ or

$$z_0^2 = 8 \left[\left(\frac{\Delta L}{L} \right) - \left(\frac{\Delta L}{L} \right)_c \right] / 3 k_c^2. \quad (14)$$

With this amplitude and with $(\Delta L/L)_c$ from Eqs. (9) and (11) put into Eq. (4), we find for the *rippled skin* an average free energy per unit area

$$f_1 = f_0 - \frac{1}{3} \bar{B} d \left[\left(\frac{\Delta L}{L} \right) - \left(\frac{\Delta L}{L} \right)_c \right]^2 \quad (15)$$

where

$$f_0 = \frac{1}{2} \bar{B} d (\Delta L/L)^2 \quad (16)$$

is the average free energy per unit-area for the *plane skin*. In Fig. 3 f_0 and f_1 are plotted as a function of $(\Delta L/L)$. At $(\Delta L/L)_c$ both curves meet without intersection. This is typical for a second order transition. The dashed part of f_1 is physically impossible because from (Eq. (14)) the ripple amplitude would become imaginary. Experimental attempts to detect the periodic ripples and to prove the 1/4th power law between λ_c and d have been initiated.

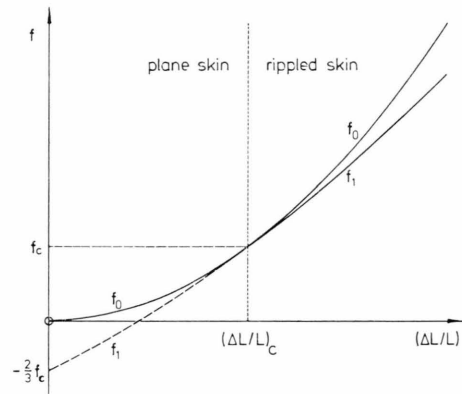


Fig. 3. Average free energy per unit-area f as a function of compressive strain $(\Delta L/L)$. f_0 from Eq. (16), f_1 from Equation (15).

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